TOSHIBA Photocoupler GaAs Ired & Photo-Transistor

# **TLP141G**

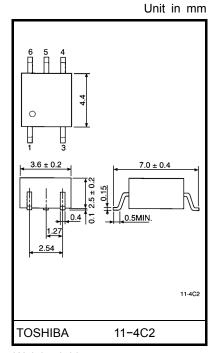
Programmable Controllers
AC-Output Module
Solid State Relay

The TOSHIBA mini flat coupler TLP141G is a small outline coupler, suitable for surface mount assembly.

The TLP141G consists of a photo thyristor, optically coupled to a gallium arsenide infrared emitting diode.

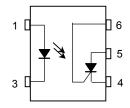
Peak off-state voltage: 400 V (min.)
Trigger LED current: 10 mA (max.)
On-state current: 150 mA (max.)

Isolation voltage: 2500 Vrms (min.)
UL recognized: UL1577, file no. E67349



Weight: 0.09 g

#### **Pin Connections**



- 1 : Anode
- 3 : Cathode
- 4 : Cathode
- 5: Anode.
- 6: Gate

### Absolute Maximum Ratings (Ta = 25°C)

Characteristic		Symbol	Rating	Unit	
TED	Forward current	l <sub>F</sub>	50	mA	
	Forward current derating (Ta ≥ 53°C)	ΔI <sub>F</sub> /°C	-0.7	mA / °C	
	Peak forward current (100 µs pulse, 100 pps)	I <sub>FP</sub>	1	Α	
	Reverse voltage	V <sub>R</sub>	5	V	
	Junction temperature	Tj	125	°C	
	Peak forward voltage(R <sub>GK</sub> = 27kΩ)	$V_{DRM}$	400	V	
	Peak reverse voltage( $R_{GK} = 27k\Omega$ )	$V_{DRM}$	400	٧	
ō	On–state current	I <sub>T(RMS)</sub>	150	mA	
Detector	On–state current derating (Ta ≥ 25°C)	ΔI <sub>T</sub> / °C	-2.0	mA / °C	
	Peak one cycle surge current	I <sub>TSM</sub>	2	Α	
	Peak reverse gate voltage	$V_{GM}$	5	V	
	Junction temperature	Tj	100	°C	
Storag	e temperature range	T <sub>stg</sub>	-55~125	°C	
Operat	ing temperature range	T <sub>opr</sub>	-55~100	°C	
Lead s	oldering temperature (10 s)	T <sub>sol</sub>	260	°C	
Isolation voltage (AC, 1 min., RH ≤ 60%) (Note 1)		$BV_S$	2500	Vrms	

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

(Note 1) Device considered a two terminal device: pins 1 and 3 shorted together and pins 4, 5 and 6 shorted together.

### **Recommended Operating Conditions**

Characteristic	Symbol	Min.	Тур.	Max.	Unit
Supply voltage	V <sub>AC</sub>	_	_	120	Vac
Forward current	lF	15	20	25	mA
Operating temperature	T <sub>opr</sub>	-25	_	85	°C
Gate to cathode resistance	R <sub>GK</sub>	_	27	33	kΩ
Gate to cathode capacitance	C <sub>GK</sub>	_	0.01	0.1	μF

Note: Recommended operating conditions are given as a design guideline to obtain expected performance of the device. Additionally, each item is an independent guideline respectively. In developing designs using this product, please confirm specified characteristics shown in this document.

# Individual Electrical Characteristics (Ta = 25°C)

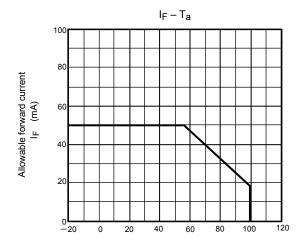
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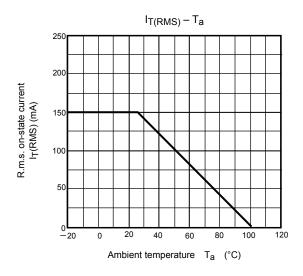
Characteristic		Symbol	Test Condition		Min.	Тур.	Max.	Unit
LED	Forward voltage	V <sub>F</sub>	I <sub>F</sub> = 10 mA		1.0	1.15	1.3	V
	Reverse current	I <sub>R</sub>	V <sub>R</sub> = 5 V		_	_	10	μΑ
	Capacitance	C <sub>T</sub>	V = 0, f = 1 MHz		_	30	_	pF
Detector	Off-state current	I <sub>DRM</sub>	V <sub>AK</sub> = 400 V R <sub>GK</sub> = 27 kΩ	Ta = 25°C	_	10	5000	nA
				Ta = 100°C	_	1	100	μA
	Reverse current	I <sub>RRM</sub>	V <sub>KA</sub> = 70 mA	Ta = 25°C	_	10	5000	nA
			$R_{GK} = 27 k\Omega$	Ta = 100°C	_	1	100	μA
	On-state voltage	V <sub>TM</sub>	I <sub>TM</sub> = 100 mA		_	0.9	1.3	V
	Holding current	lΗ	R <sub>GK</sub> = 27 kΩ		_	0.2	1	mA
	Off–state dv / dt	dv/dt	$V_{AK} = 280 \text{ V}, R_{GK} = 27 \text{ k}\Omega$		5	10	_	V / µs
	Capacitance $C_j$ $V = 0, f = 0$	C.	V = 0, f = 1 MHz	Anode to gate	_	20	_	nE.
		V = 0, 1 = 1 WHZ	Gate to cathode	_	350	_	pF	

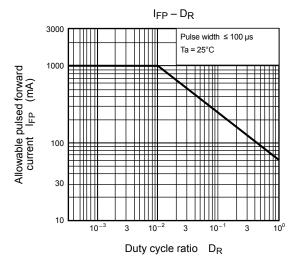
# Coupled Characteristics (Ta = 25°C)

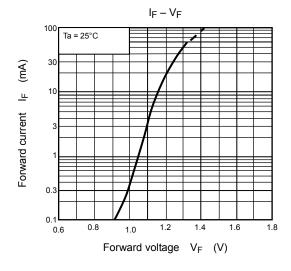
Characteristic	Symbol	Test Condition	Min.	Тур.	Max.	Unit
Trigger LED current	I <sub>FT</sub>	$V_{AK}$ = 6 V, $R_{GK}$ = 27k $\Omega$	_	4	10	mA
Turn-on time	t <sub>on</sub>	$I_F$ = 50mA, $R_{GK}$ = 27kΩ	_	10	_	μs
Coupled dv / dt	dv/dt	$V_S = 500 \text{ V}, R_{GK} = 27 \text{k}\Omega$	500	_	_	V / µs
Capacitance (input to output) C <sub>S</sub> V <sub>S</sub>		V <sub>S</sub> = 0, f = 1 MHz	_	0.8	_	pF
Isolation resistance	R <sub>S</sub>	V <sub>S</sub> = 500 V, R.H. ≤ 60%	5×10 <sup>10</sup>	10 <sup>14</sup>	_	Ω
		AC, 1 minute	2500	_	_	Vrms
Isolation voltage		AC, 1 second, in oil	_	5000	_	VIIIIS
		DC, 1 minute, in oil	_	5000	_	Vdc

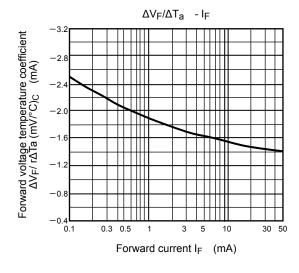
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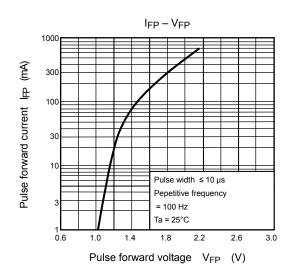


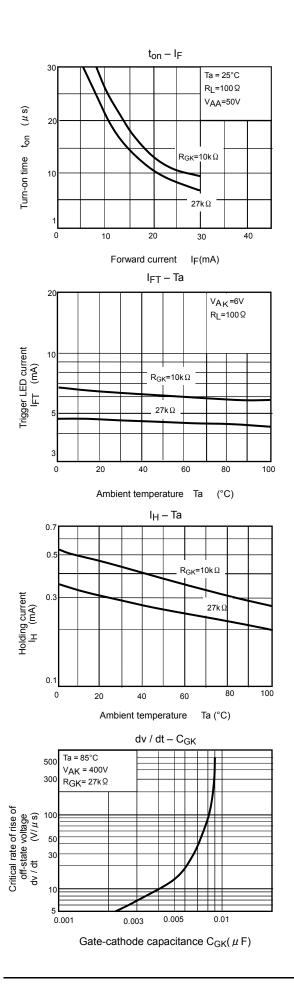


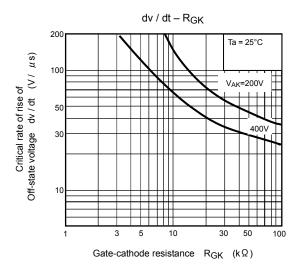


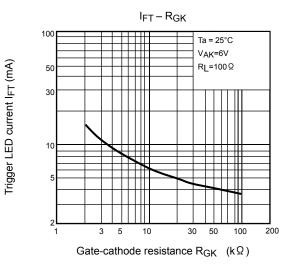


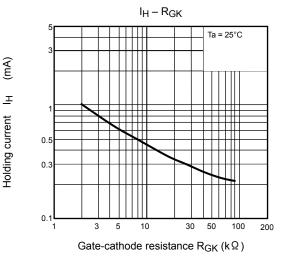












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